

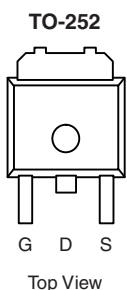
P-Channel 30-V (D-S), MOSFET

PRODUCT SUMMARY

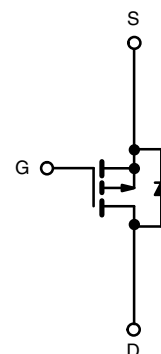
V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A) ^a
- 30	0.010 at $V_{GS} = - 10$ V	- 15
	0.018 at $V_{GS} = - 4.5$ V	- 12

FEATURES

- TrenchFET® Power MOSFETs


RoHS
COMPLIANT


Ordering Information: SUD45P03-10-E3 (Lead (Pb)-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	- 30	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ^b	I_D	$T_A = 25$ °C	A
		$T_A = 100$ °C	
Pulsed Drain Current	I_{DM}	- 100	
Continuous Source Current (Diode Conduction)	I_S	- 15	
Maximum Power Dissipation ^b	P_D	$T_C = 25$ °C	W
		$T_A = 25$ °C	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to 150	°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^b	R_{thJA}		30	°C/W
Maximum Junction-to-Case	R_{thJC}		1.8	

Notes:

a. Calculated Rating for $T_A = 25$ °C, for comparison purposes only. This cannot be used as continuous rating (see Absolute Maximum Ratings and Typical Characteristics).

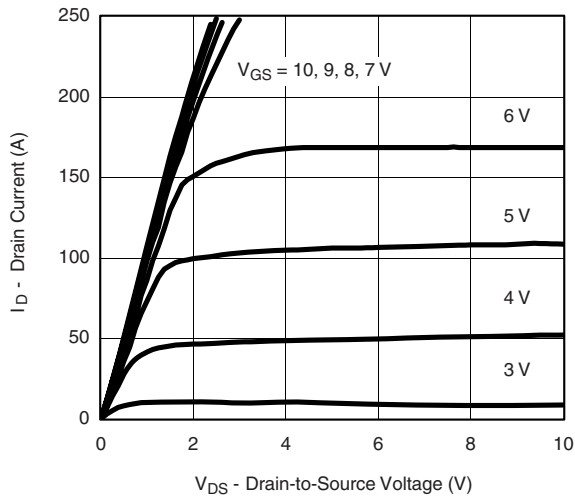
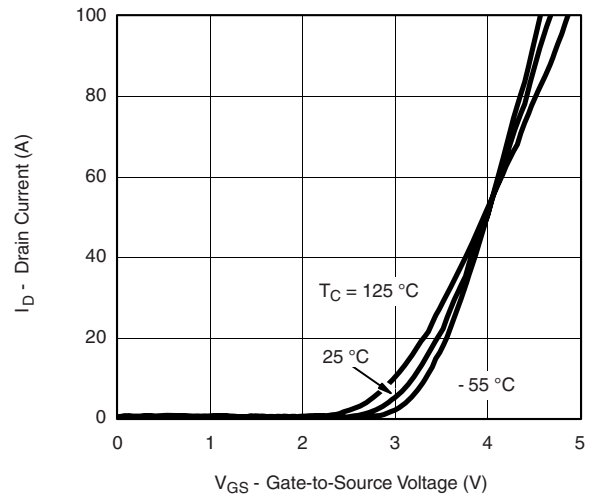
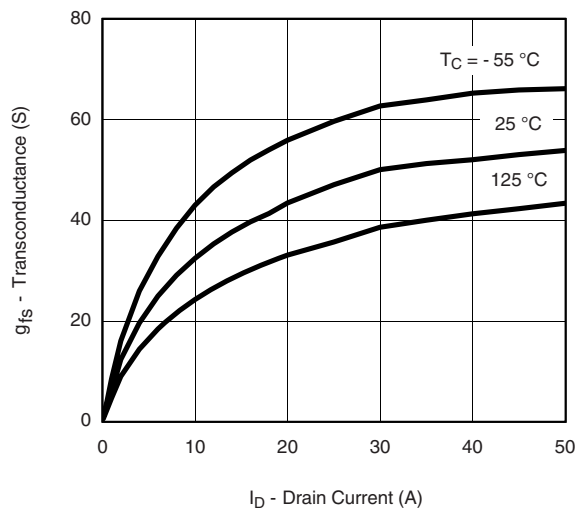
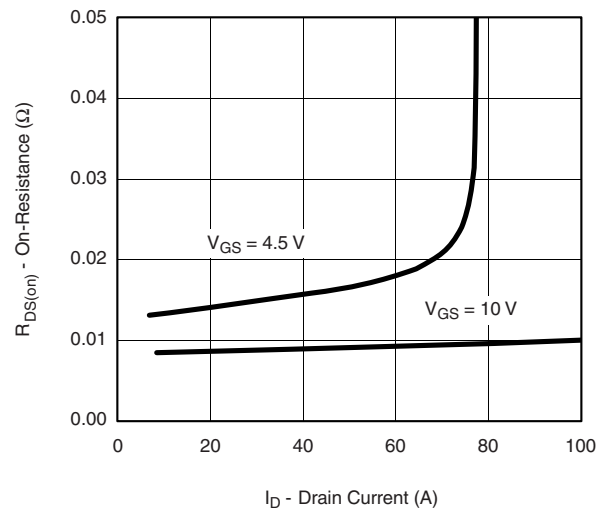
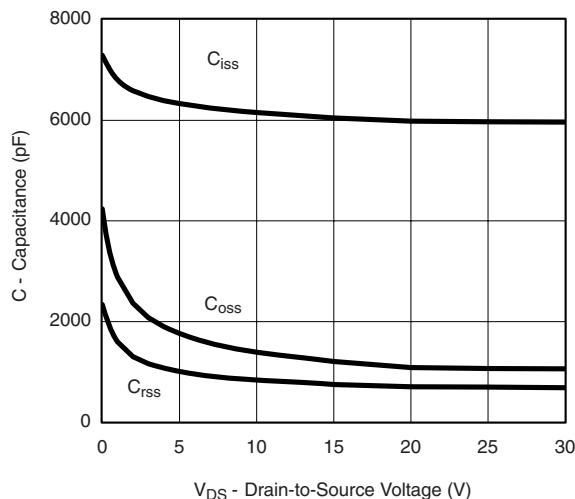
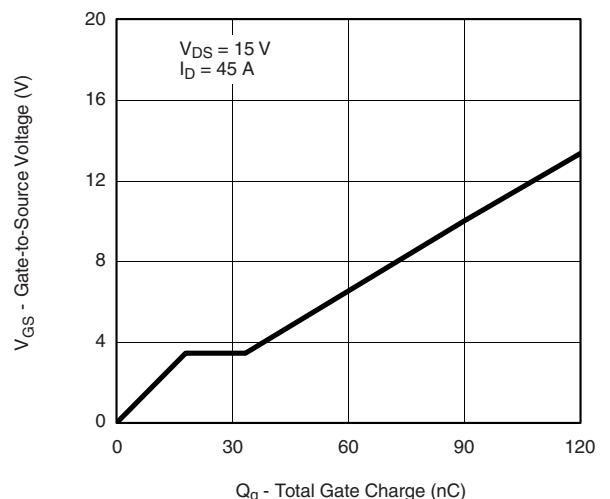
b. Surface Mounted on FR4 board, $t \leq 10$ s.

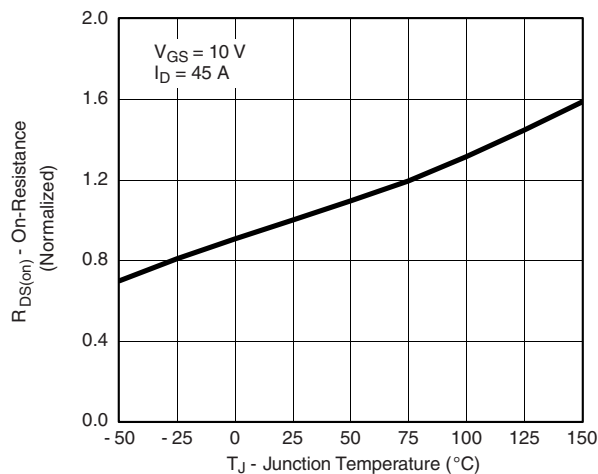
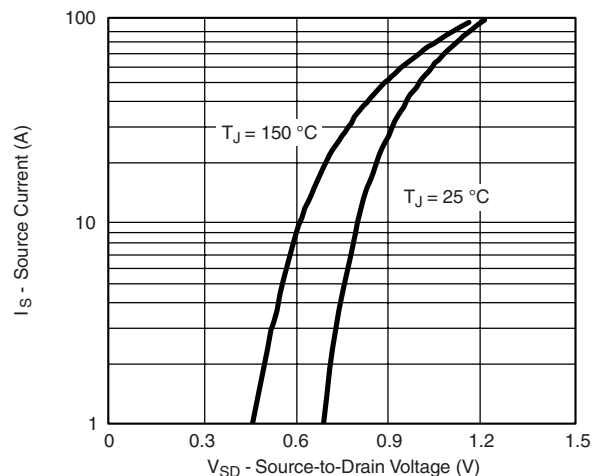
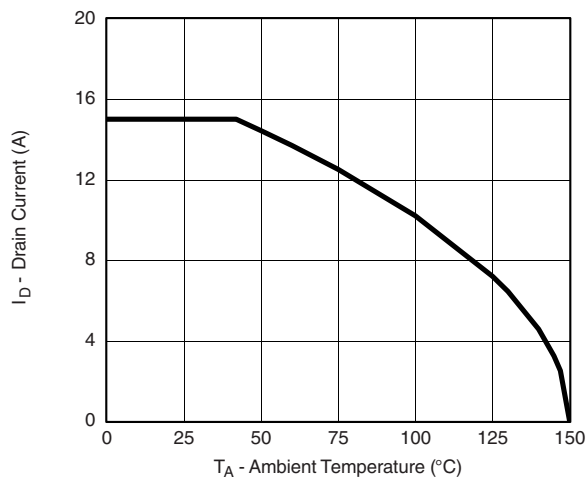
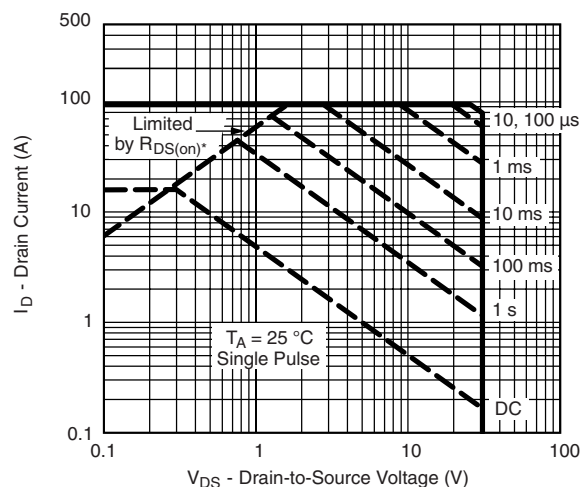
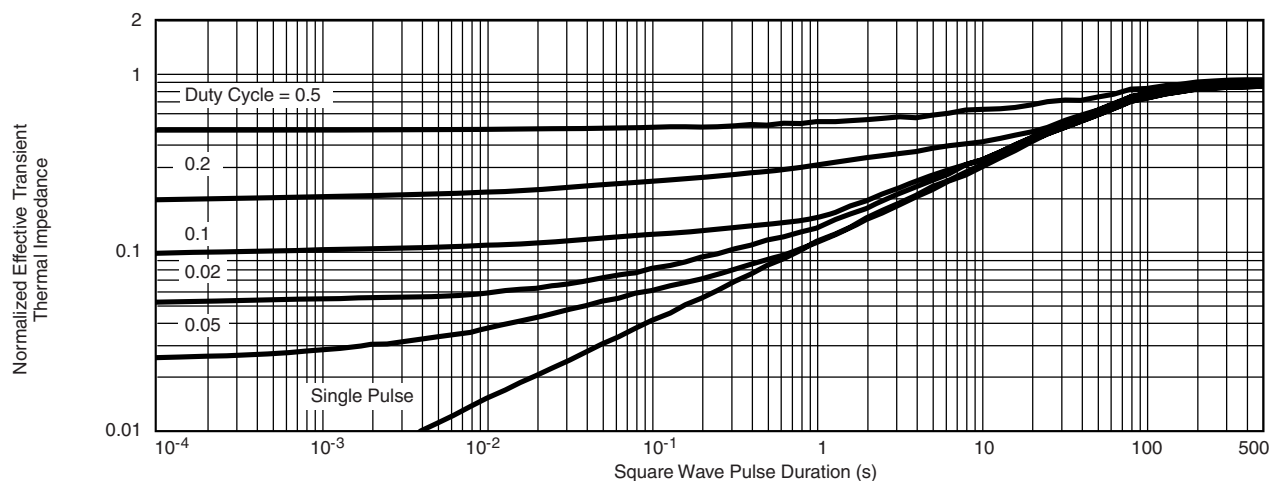
SPECIFICATIONS T _J = 25 °C, unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = - 250 μA	- 30			V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = - 250 μA	- 1.0		- 3.0	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 30 V, V _{GS} = 0 V			- 1	μA
		V _{DS} = - 30 V, V _{GS} = 0 V, T _J = 125 °C			- 50	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	- 50			A
		V _{DS} = - 5 V, V _{GS} = - 4.5 V	- 20			
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 15 A			0.010	Ω
		V _{GS} = - 10 V, I _D = - 15 A, T _J = 125 °C			0.015	
		V _{GS} = - 4.5 V, I _D = - 15 A			0.018	
Forward Transconductance ^a	g _{fs}	V _{DS} = - 15 V, I _D = - 15 A	20			S
Dynamic ^b						
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = - 25 V, f = 1 MHz		6000		pF
Output Capacitance	C _{oss}			1100		
Reverse Transfer Capacitance	C _{rss}			700		
Total Gate Charge ^c	Q _g	V _{DS} = - 15 V, V _{GS} = - 10 V, I _D = - 45 A		90	150	nC
Gate-Source Charge ^c	Q _{gs}			20		
Gate-Drain Charge ^c	Q _{gd}			16		
Turn-On Delay Time ^c	t _{d(on)}	V _{DD} = - 15 V, R _L = 0.33 Ω I _D ≅ - 45 A, V _{GEN} = - 10 V, R _G = 2.4 Ω		15	25	ns
Rise Time ^c	t _r			375	550	
Turn-Off Delay Time ^c	t _{d(off)}			100	200	
Fall Time ^c	t _f			140	250	
Source-Drain Diode Ratings and Characteristic T _C = 25 °C						
Pulsed Current	I _{SM}				100	A
Diode Forward Voltage ^a	V _{SD}	I _F = - 45 A, V _{GS} = 0 V		1.0	1.5	V
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 45 A, dI/dt = 100 A/μs		55	100	ns

Notes:

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Output Characteristics

Transfer Characteristics

Transconductance

On-Resistance vs. Drain Current

Capacitance

Gate Charge

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted**On-Resistance vs. Junction Temperature****Source-Drain Diode Forward Voltage****THERMAL RATINGS****Maximum Drain Current
vs. Ambient Temperature*** $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified**Safe Operating Area****Normalized Thermal Transient Impedance, Junction-to-Ambient**

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TO-252AA Case Outline

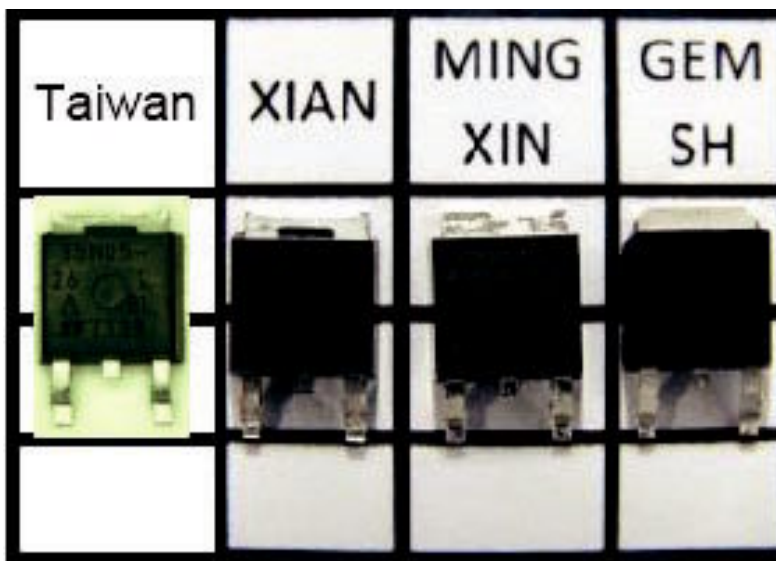


DIM.	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	2.18	2.38	0.086	0.094
A1	-	0.127	-	0.005
b	0.64	0.88	0.025	0.035
b2	0.76	1.14	0.030	0.045
b3	4.95	5.46	0.195	0.215
C	0.46	0.61	0.018	0.024
C2	0.46	0.89	0.018	0.035
D	5.97	6.22	0.235	0.245
D1	4.10	-	0.161	-
E	6.35	6.73	0.250	0.265
E1	4.32	-	0.170	-
H	9.40	10.41	0.370	0.410
e	2.28 BSC		0.090 BSC	
e1	4.56 BSC		0.180 BSC	
L	1.40	1.78	0.055	0.070
L3	0.89	1.27	0.035	0.050
L4	-	1.02	-	0.040
L5	1.01	1.52	0.040	0.060

ECN: T13-0359-Rev. O, 03-Jun-13
DWG: 5347

Notes

- Dimension L3 is for reference only.
- Xi'an, Mingxin, and GEM SH actual photo.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads
Dimensions in Inches/(mm)

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